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- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-423-B and -232-E and ITU Recommendations V.10 and V.28
- Output Slew Rate Control
- Output Short-Circuit-Current Limiting
- Wide Supply Voltage Range
- 8-Pin Package
- Designed to Be Interchangeable With National DS9636A

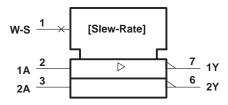
D OR P PACKAGE

description

The uA9636AC is a dual, single-ended line driver designed to meet ANSI Standards EIA/TIA-423-B and EIA/TIA-232-E and ITU Recommendations V.10 and V.28. The slew rates of both amplifiers are controlled by a single external resistor, $R_{(WS)}$, connected between the wave-shape-control (W-S) terminal and GND. Output current limiting is provided. Inputs are compatible with TTL and CMOS and are diode protected against negative transients. This device operates from ± 12 V and is supplied in an 8-pin package.

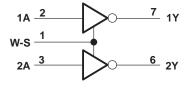
The uA9636AC is characterized for operation from 0°C to 70°C.

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram

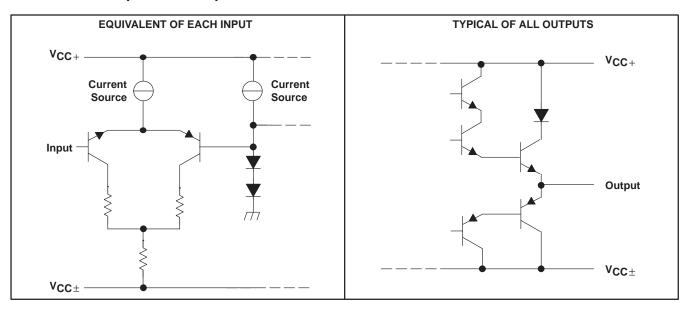




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schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Positive supply voltage range, V _{CC+} (see Note 1)	V _{CC} to 15 V
Negative supply voltage range, V _{CC}	0.5 V to –15 V
Output voltage, VO	±15 V
Output current, IO	±150 mA
Continuous total power dissipation	See Dissipation Rating Table
Continuous total power dissipation	·
·	0°C to 70°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to the network ground terminal.

DISSIPATION RATING TABLE

PACKAGE T _A ≤ 25°C POWER RATING		DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING		
D	725 mW	5.8 mW/°C	464 mW		
Р	1000 mW	8.0 mW/°C	640 mW		

recommended operating conditions

	MIN	NOM	MAX	UNIT
Positive supply voltage, V _{CC+}	10.8	12	13.2	V
Negative supply voltage, V_{CC-}	-10.8	-12	-13.2	V
High-level input voltage, V _{IH}	2			V
Low-level input voltage, V _{IL}			0.8	V
Wave-shaping resistor, R _(WS)	10		1000	kΩ
Operating free-air temperature, T _A	0		70	°C



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electrical characteristics over recommended ranges of free-air temperature, supply voltage, and wave-shaping resistance (unless otherwise noted)

PARAMETER TEST CONDITIONS		MIN	TYP [†]	MAX	UNIT		
VIK	Input clamp voltage	$I_{I} = -15 \text{ mA}$			-1.1	-1.5	V
			R _L = ∞	5	5.6	6	
∨он	High-level output voltage	V _I = 0.8 V	$R_L = 3 \text{ k}\Omega \text{ to GND}$	5	5.6	6	V
			$R_L = 450 \Omega$ to GND	4	5.4	6	1
			R _L = ∞	-6‡	-5.7	-5	V
VOL	Low-level output voltage	V _I = 2 V	$R_L = 3 \text{ k}\Omega \text{ to GND}$	-6‡	-5.6	-5	
			$R_L = 450 \Omega$ to GND	-6‡	-5.4	-4	
	High level input ourrent	V _I = 2.4 V				10	
lιΗ	High-level input current	V _I = 5.5 V				100	μΑ
I _I L	Low-level input current	V ₁ = 0.4 ∨			-20	-80	μΑ
IO	Output current (power off)	$V_{CC\pm} = 0$, $V_{O} = \pm 6 V$				±100	μΑ
3		V _I = 2 V		15	25	150	A
los	Short-circut output current§	V _I = 0		-15	-40	-150	mA
rO	Output resistance	R _L = 450 Ω			25	50	Ω
ICC+	Positive supply current	$V_{CC} = \pm 12 \text{ V},$ $R_{(WS)} = 100 \text{ k}\Omega,$	V _I = 0, Output open		13	18	mA
ICC-	Negative supply current	$V_{CC} = \pm 12 \text{ V},$ $R_{(WS)} = 100 \text{ k}\Omega,$	V _I = 0, Output open		-13	-18	mA

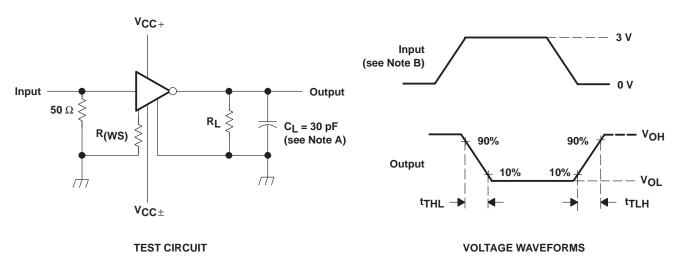
switching characteristics, $V_{CC\pm}$ = ± 12 V, T_A = $25^{\circ}C$ (see Figure 1)

PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT			
Transition time law to high level output				$R(WS) = 10 k\Omega$	8.0	1.1	1.4	
	D. 450 kg. C. 20 pF	$R_{(WS)} = 100 \text{ k}\Omega$	8	11	14			
TH	t _{TLH} Transition time, low- to high-level output	$R_L = 450 \text{ k}\Omega, C_L = 30 \text{ pF}$	$R_{(WS)} = 500 \text{ k}\Omega$	40	55	70	μs	
				$R(WS) = 1 M\Omega$	80	110	140	
t _{THL} Transition time, high- to low-level output			$R(WS) = 10 k\Omega$	0.8	1.1	1.4		
	$R_1 = 450 \text{ k}\Omega, C_1 = 30 \text{ pF}$	$R(WS) = 100 k\Omega$	8	11	14			
	Transition time, high- to low-level output	K[= 450 K22, C	= 450 kΩ, C_L = 30 pF	$R(WS) = 500 k\Omega$	40	55	70	μs
				$R_{(WS)} = 1 M\Omega$	80	110	140	

[†] All typical values are at V_{CC} = ±12 V, T_A = 25°C. ‡ The algebraic convention, in which the less-positive (more-negative) limit is designated as minimum, is used in this data sheet for logic voltage levels, e.g., when -5 V is the maximum, the minimum is a more-negative voltage.

 $[\]S$ Not more than one output should be shorted to ground at a time.

PARAMETER MEASUREMENT INFORMATION

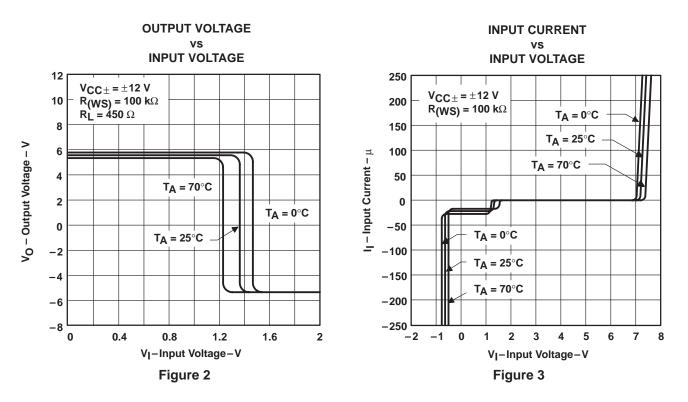


NOTES: A. C_L includes probe and jig capacitance.

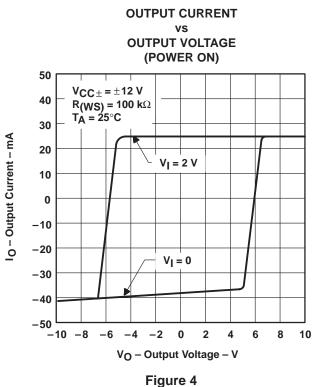
B. The input pulse is supplied by a generator having the following characteristics: $t_r \le 10$ ns, $t_f \le 10$ ns, $Z_O = 50 \Omega$, PRR ≤ 1 kHz, duty cycle = 50%.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



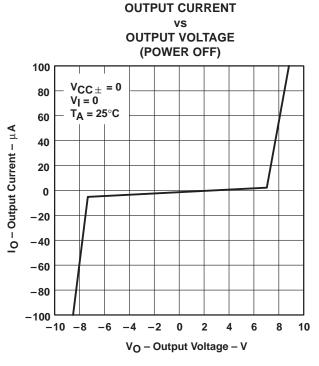


Figure 5

TRANSITION TIME vs WAVE-SHAPING RESISTANCE

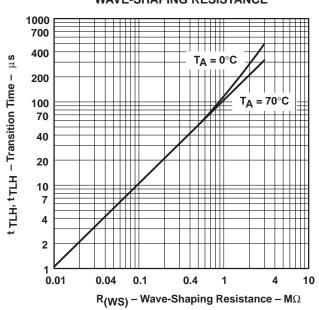




Figure 6

APPLICATION INFORMATION

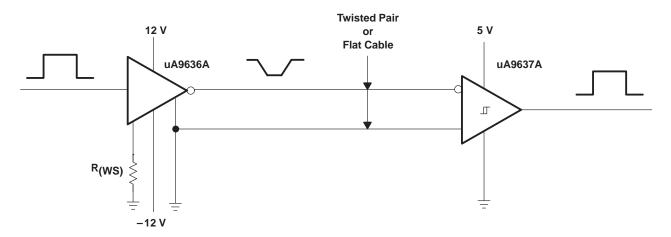


Figure 7. EIA/TIA-423-B System Application

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